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With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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## KSB1097

## **Low Frequency Power Amplifier**

- Low Speed Switchng Industrial Use
- Complement to KSD1588



## **PNP Epitaxial Silicon Transistor**

### Absolute Maximum Ratings T<sub>C</sub>=25°C unless otherwise noted

Symbol	Parameter	Value	Units
V <sub>CBO</sub>	Collector-Base Voltage	- 80	V
V <sub>CEO</sub>	Collector-Emitter Voltage	- 60	V
V <sub>EBO</sub>	Emitter-Base Voltage	- 7	V
I <sub>C</sub>	Collector Current (DC)	- 7	Α
I <sub>CP</sub>	*Collector Current (Pulse)	- 15	Α
I <sub>B</sub>	Base Current	- 3.5	Α
P <sub>C</sub>	Collector Dissipation (T <sub>a</sub> =25°C)	2	W
P <sub>C</sub>	Collector Dissipation (T <sub>C</sub> =25°C)	30	W
T <sub>J</sub>	Junction Temperature	150	°C
T <sub>STG</sub>	Storage Temperature	- 55 ~ 150	°C

<sup>\*</sup> PW≤300μs, Duty Cycle≤10%

### Electrical Characteristics T<sub>C</sub>=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Max.	Units
I <sub>CBO</sub>	Collector Cut-off Current	$V_{CB} = -60 V, I_{E} = 0$		- 10	μΑ
I <sub>EBO</sub>	Emitter Cut-off Current	$V_{EB} = -5V, I_{C} = 0$		- 10	μΑ
h <sub>FE1</sub>	* DC Current Gain	$V_{CE} = -1V, I_{C} = -3A$	40	200	
h <sub>FE2</sub>		$V_{CE} = -1V, I_{C} = -5A$	20		
V <sub>CE</sub> (sat)	Collector-Emitter Saturation Voltage	$I_C = -5A, I_B = -0.5A$		- 0.5	V
V <sub>BE</sub> (sat)	* Base-Emitter Saturation Voltage	$I_C = -5A, I_B = -0.5A$		- 1.5	V

<sup>\*</sup> Pulse Test: PW≤350μs, Duty Cycle≤2% Pulsed

## **h**<sub>FE</sub> Classification

Classification	R	0	Y
h <sub>FE1</sub>	40 ~ 80	60 ~ 120	100 ~ 200

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# **Typical Characteristics**

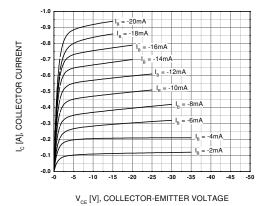


Figure 1. Static Characteristics

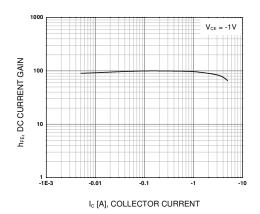


Figure 2. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

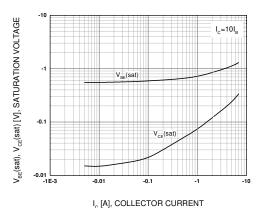


Figure 3. Saturation Voltage

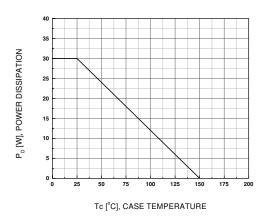


Figure 4. Power Derating

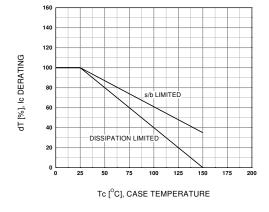


Figure 5. Power Derating

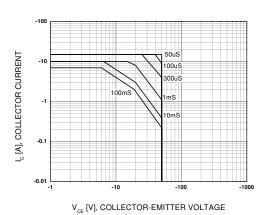
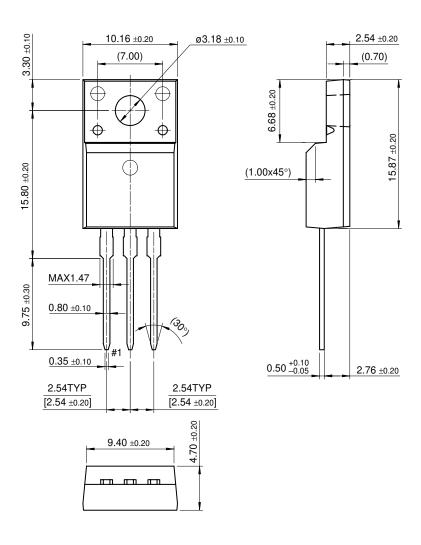


Figure 6. Safe Operating Area

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# **Package Demensions**

# TO-220F



Dimensions in Millimeters

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No Identification Needed	Full Production	This datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
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